### 2.0A GLASS PASSIVATED BRIDGE RECTIFIE

## Data Sheet 1400, Rev.—

### **Green Products**

### **Features**

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- Ideal for Printed Circuit Boards
- UL Recognized File # E223064
- Green Products in Compliance with the RoHS Directive

### **Mechanical Data**

Case: Molded Plastic

Terminals: Plated Leads Solderable per

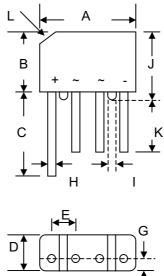
MIL-STD-202, Method 208

Polarity: As Marked on Body
Weight: 1.7 grams (approx.)

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Mounting Position: Any
 Marking Trans Name In and

Marking: Type Number



КВР						
Dim	Min	Max	Min	Max		
Α	14.22	15.24	0.560	0.6		
В	10.67	11.68	0.420	0.460		
С	15.2	_	0.598	_		
D	4.57	5.08	0.180	0.2		
Е	3.60	4.10	0.142	0.161		
G	2.16	2.67	0.085	0.105		
Н	0.76	0.86	0.030	0.034		
ı	1.52	_	0.060	_		
J	11.68	12.7	0.460	0.5		
K	12.7	_	0.5	_		
L	3.2 X 45°C Typical		0.126 X 45°C Typical			
	In mm		In inch			

Maximum Rati	ngs and Electrical	Characteristics	@T₄=25°C unless otherwise specified
ıvıaxımıum Rau	nus and Electrical	Characteristics	(a) L <sub>A</sub> =25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	2KBP 005M-G	2KBP 01M-G	2KBP 02M-G	2KBP 04M-G	2KBP 06M-G	2KBP 08M-G	2KBP 10M-G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	200	400	600	800	1000	٧
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @T <sub>A</sub> = 50°	c lo	2.0					Α		
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	60					Α		
Forward Voltage (per element) @I <sub>F</sub> = 2.0A	A VFM	VFM 1.1				V			
Peak Reverse Current @T <sub>A</sub> = 25° At Rated DC Blocking Voltage @T <sub>A</sub> = 100°		10 500					μA		
Rating for Fusing (t<8.3ms)	l <sup>2</sup> t	15					A <sup>2</sup> s		
Typical Junction Capacitance per element (Note 2)	Cj	25					pF		
Typical Thermal Resistance (Note 3)	$R_{ heta}$ JA	30					K/W		
Operating and Storage Temperature Range	Тj, Tsтg	-55 to +165					°C		

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
- 3. Thermal resistance junction to ambient mounted on PC board with 12mm<sup>2</sup> copper pad.

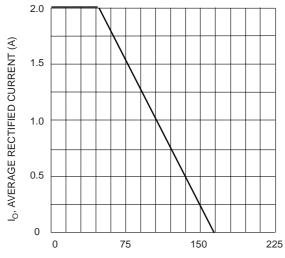
<sup>• 221</sup> West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FAX (631) 242-9798 •

<sup>•</sup> World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •

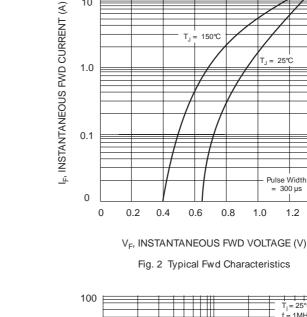
150℃

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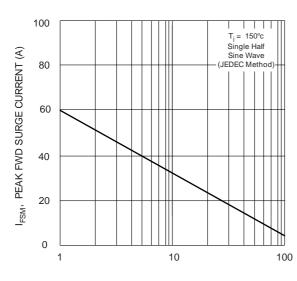
### **Green Products**



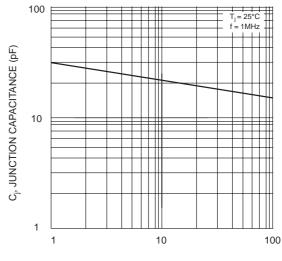
T, TEMPERATURE (°C) Fig. 1 Forward Current Derating Curve



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NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Fwd Surge Current



V<sub>R</sub>, REVERSE VOLTAGE (V) Fig. 4 Typical Junction Capacitance

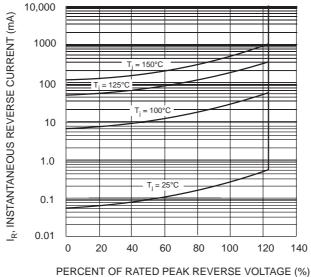


Fig. 5 Typical Reverse Characteristics

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#### 2KBP005M-G - 2KBP10M-G

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